
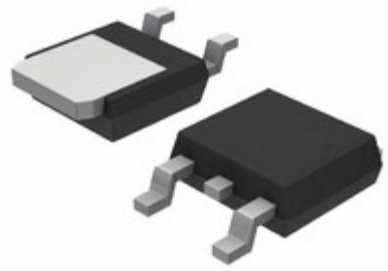
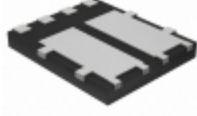
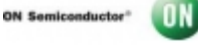
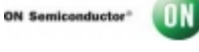
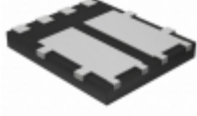
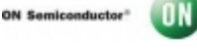

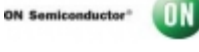

	<h2>NRVHPD660T4G</h2>
	<p>Hersteller-Teilenummer: NRVHPD660T4G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: DIODE GEN PURP 600V 6A DPAK</p> <hr/> <p>Datenblätter:  NRVHPD660T4G.pdf</p> <hr/> <p>RoHS Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 15000 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NRVHPD660T4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	DIODE GEN PURP 600V 6A DPAK
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	15000 pcs Stock
Serie	Automotive, AEC-Q101
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Diodentyp	Standard
Strom - Richt (Io)	6A
Spannung - Forward (Vf) (Max) @ If	3V @ 6A
Strom - Sperrleckstrom @ Vr	30µA @ 600V
Spannung - Sperr (Vr) (max)	600V
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	50ns
Betriebstemperatur - Anschluss	-65°C ~ 175°C
Kapazität @ Vr, F	-
Verpackung	Tape & Reel (TR)

NRVHPD660T4G ist neu im Original, Suche NRVHPD660T4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NRVHPD660T4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NRVHPD660T4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NRVHP8H200MFD3G AMI Semiconductor / ON Semiconductor PUF 4A 200V IN SO-8FL DUA</p>	 <p>NRVHPRS1DFA AMI Semiconductor / ON Semiconductor SR SOD123FA PN 0.8A 200V</p>	 <p>NRVHPRS1AFA AMI Semiconductor / ON Semiconductor SR SOD123FA PN 0.8A 50V</p>	 <p>NRVHP8H200MFDWFT3G AMI Semiconductor / ON Semiconductor PUF 4A 200V IN SO-8FL DUA</p>
 <p>NRVHPAF220T3G AMI Semiconductor / ON Semiconductor NRVHPAF220T3G ON</p>	 <p>NRVHPM220T3G AMI Semiconductor / ON Semiconductor DIODE GEN PURP 200V 2A POWERMITE</p>	 <p>NRVHPAF320T3G AMI Semiconductor / ON Semiconductor NRVHPAF320T3G ON</p>	 <p>NRVHPM120T3G AMI Semiconductor / ON Semiconductor DIODE GEN PURP 200V 1A POWERMITE</p>

heiße Teile

Mehr

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 BZX384B3V9-GS08	 BZX384C3V3	 EGF1THE3/67A	 ES542C-YDC	 IS43TR81280A-15GBLI
 LAH100-TP/SP3	 MA101000L	 MCR100-6M	 MIC1810-15U	 MMBZ39VA
 D NRV2010T4R7MGF	 NRV2012T2R2MGF	 NRV2012T2R2MGF	 NRV2012T4R7MGF	 NRV2012T4R7MGF
 NRV3012T100M	 NRV3012T1R0N	 NRV3012T1R5N	 NRV3012T2R2MV	 NRV3012T3R3M
 NRV3012T3R3M	 NRVA4004T3G	 D NRVA4005T3G	 NRVA4006T3G	 NRVA4007T3G
 NRVBA120ET3G	 D NRVBA130LT3G	 NRVBA160T3G	 NRVBA210LT3G	 NRVBA340T3G
 NRVBAF1540T3G	 NRVBB1060T4G	 NRVHP120SFT3G	 NRVHP220SFT3G	 NRVHP220SFT3G
 NRVHP620MFD1G	 NRVHP620MFD3G	 NRVHPAF220T3G	 D NRVHPAF320T3G	 NRVUS230T3G
 NRVUS240T3G	 NSV40301MZ4T1G	 PAM3130BEC150	 SX1502I087TRT	 TL322IDR

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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